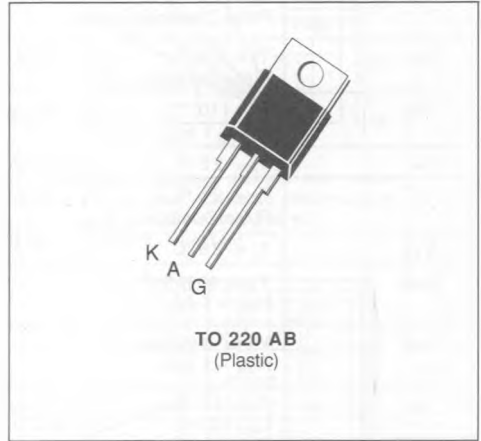




## SENSITIVE GATE THYRISTORS

- OPERATES DIRECTLY FROM LOW SIGNAL
- GLASS PASSIVATED CHIP
- POSSIBILITY OF MOUNTING ON PRINTED CIRCUIT



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state Current (1)	$T_c = 75^\circ\text{C}$ 6	A
$I_{T(AV)}$	Mean on-state Current (1)	$T_c = 75^\circ\text{C}$ 3.8	A
$I_{TSM}$	Non Repetitive Surge Peak on-state Current ( $T_j$ initial = $25^\circ\text{C}$ ) (2)	$t = 8.3\text{ ms}$	52
		$t = 10\text{ ms}$	50
$I^2t$	$I^2t$ Value for Fusing	$t = 10\text{ ms}$	$\text{A}^2\text{s}$
$di/dt$	Critical Rate of Rise of on-state Current (3)	100	$\text{A}/\mu\text{s}$
$T_{stg}$ $T_j$	Storage and Operating Junction Temperature Range	- 40 to 110 - 40 to 110	$^\circ\text{C}$ $^\circ\text{C}$

Symbol	Parameter	TYS606... or TYS607-..						Unit
		05	1	2	4	6	8	
$V_{DRM}$ $V_{RRM}$	Repetitive Peak off-state Voltage (4)	50	100	200	400	600	800	V

- (1) Single phase circuit,  $180^\circ$  conduction angle.  
 (2) Half sine wave.  
 (3)  $I_G = 5\text{ mA}$   $di_G/dt = 1\text{ A}/\mu\text{s}$ .  
 (4)  $T_i = 110^\circ\text{C}$   $R_{GK} = 1\text{ K}\Omega$ .

### THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction-case for DC	5.5	$^\circ\text{C}/\text{W}$
$R_{th(j-a)}$	Junction-ambient	60	$^\circ\text{C}/\text{W}$

**GATE CHARACTERISTICS** (maximum values)

$P_{GM} = 20 \text{ W}$  ( $t_p = 20 \mu\text{s}$ )

$I_{FGM} = 2 \text{ A}$  ( $t_p = 20 \mu\text{s}$ )

$V_{RGM} = 5 \text{ V}$

$P_{G(AV)} = 0.5 \text{ W}$

$V_{FGM} = 15 \text{ V}$  ( $t_p = 20 \mu\text{s}$ )

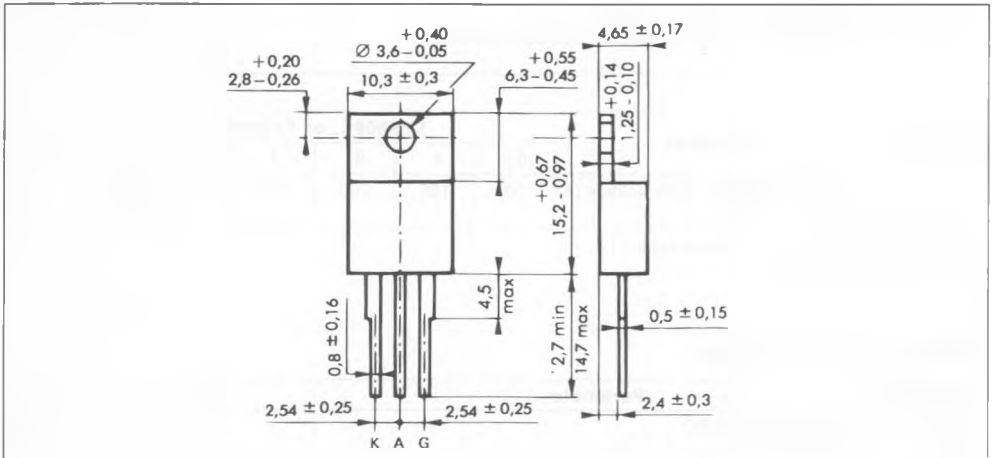
**ELECTRICAL CHARACTERISTICS**

Symbol	Types	Test Conditions	Min.	Typ.	Max.	Unit
$I_{GT}$	TYS606	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $R_L = 140 \text{ } \Omega$			0.2	mA
	TYS607	Pulse Duration > 20 $\mu\text{s}$			0.5	
$V_{GT}$		$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $R_L = 140 \text{ } \Omega$ Pulse Duration > 20 $\mu\text{s}$			1.5	V
$V_{GD}$		$T_j = 110 \text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $R_{GK} = 1 \text{ k}\Omega$	0.1			V
$I_H$		$T_j = 25 \text{ }^\circ\text{C}$ $I_T = 50 \text{ mA}$ $R_{GK} = 1 \text{ k}\Omega$			6	mA
$I_L$		$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $I_G = 10 \text{ mA}$ Pulse Duration > 20 $\mu\text{s}$ $R_{GK} = 1 \text{ k}\Omega$		10		mA
$V_{TM}$		$T_j = 25 \text{ }^\circ\text{C}$ $I_{TM} = 12 \text{ A}$ $t_p = 10 \text{ ms}$			1.85	V
$I_{DRM}$		$V_{DRM}$ specified $R_{GK} = 1 \text{ k}\Omega$	$T_j = 25 \text{ }^\circ\text{C}$		0.01	mA
			$T_j = 110 \text{ }^\circ\text{C}$		0.5	
$I_{RRM}$		$V_{RRM}$ specified $R_{GK} = 1 \text{ k}\Omega$	$T_j = 25 \text{ }^\circ\text{C}$		0.01	mA
			$T_j = 110 \text{ }^\circ\text{C}$		0.5	
$t_{gt}$		$T_j = 25 \text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $I_G = 10 \text{ mA}$ $dI_G/dt = 0.15 \text{ A}/\mu\text{s}$		12 A	1.5	$\mu\text{s}$
$t_q$		$T_j = 110 \text{ }^\circ\text{C}$ $I_T = 12 \text{ A}$ $V_R = 24 \text{ V}$ $V_D = 67\% V_{DRM}$ $dI/dt = 10 \text{ A}/\mu\text{s}$ $R_{GK} = 1 \text{ k}\Omega$ $dv/dt = 10 \text{ V}/\mu\text{s}$			100	$\mu\text{s}$
$dv/dt^*$		$T_j = 110 \text{ }^\circ\text{C}$ $R_{GK} = 1 \text{ k}\Omega$ Linear Slope up to $V_D = 67\% V_{DRM}$		10		V/ $\mu\text{s}$

\* For higher guaranteed values, please consult us.

**PACKAGE MECHANICAL DATA**

TO 220 AB Plastic



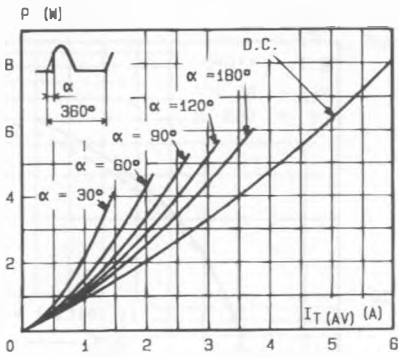


Fig.1 - Maximum mean power dissipation versus mean on-state current.

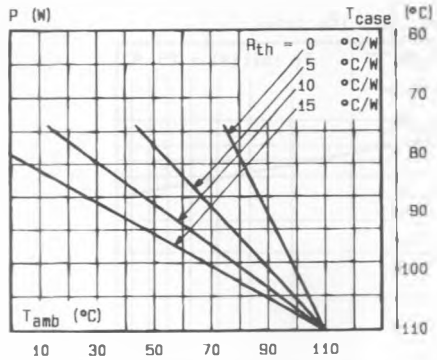


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for different thermal resistances heatsink + contact.

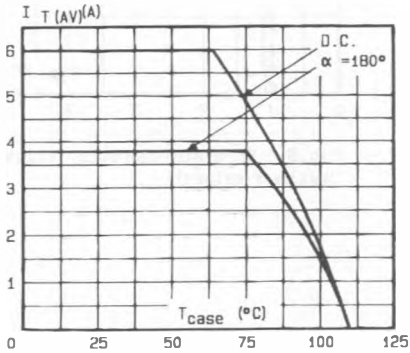


Fig.3 - Mean on-state current versus case temperature.

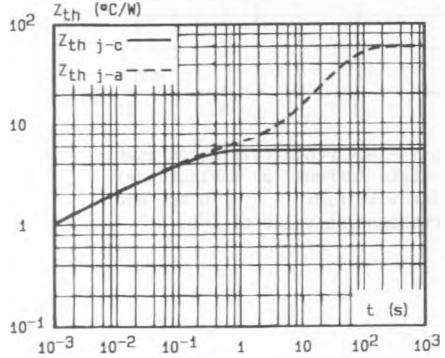


Fig.4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

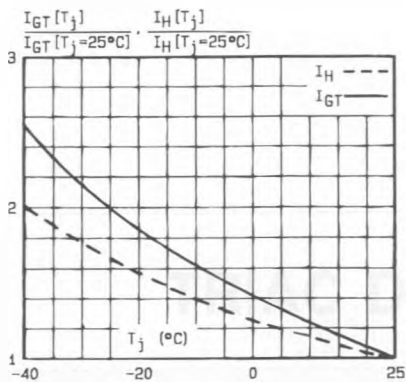


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

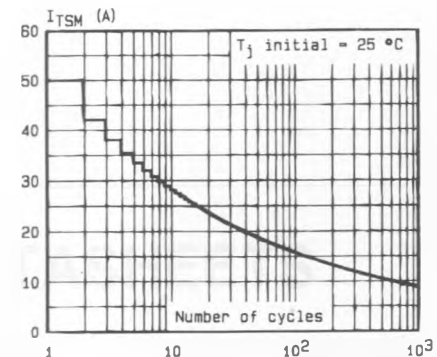


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

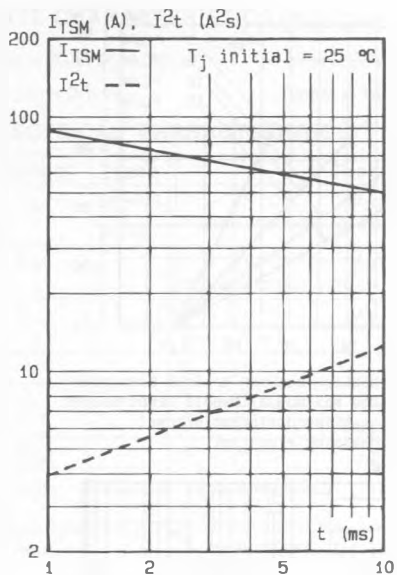


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

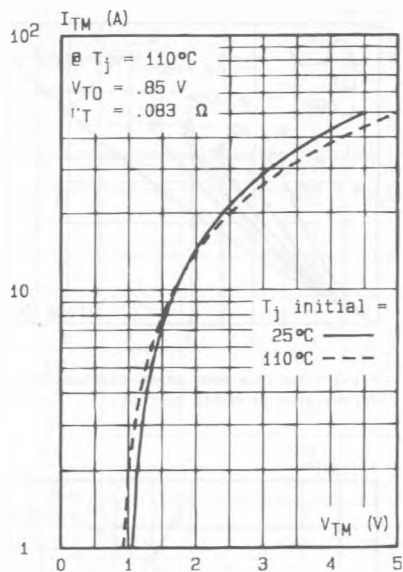


Fig.8 - On-state characteristics (maximum values).